

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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J-FET INPUT LOW-OFFSET OPERATIONAL AMPLIFIER

DESCRIPTION

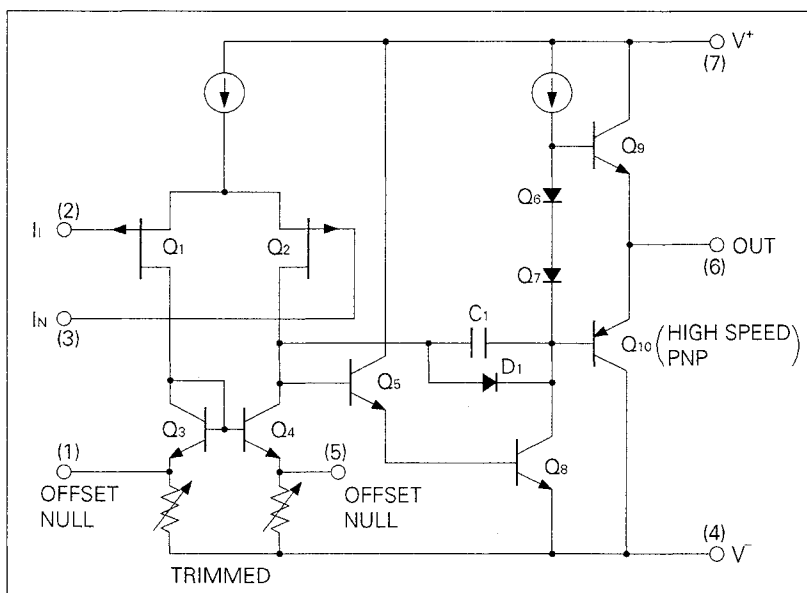
The μ PC813 operational amplifier is a high-speed version of the μ PC811. NEC's unique high-speed PNP transistor ($f_T = 300$ MHz) in the output stage yields a high slew rate of 25 V/ μ s under voltage-follower conditions without an oscillation problem. Zener-zap trimming in the input stage produces excellent offset voltage and temperature drift characteristics.

With AC performance characteristics that are two times better than conventional bi-FET op amps, the μ PC813 is ideal for fast integrators, active filters, and other high-speed circuit applications.

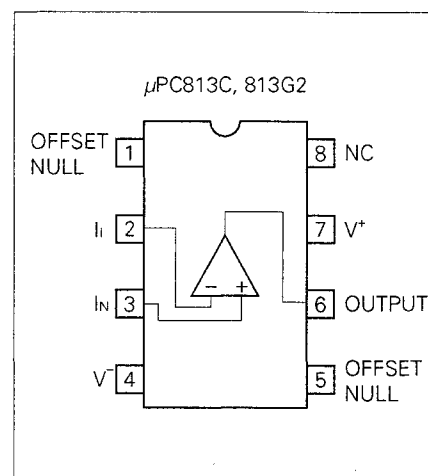
FEATURES

- High slew rate: 25 V/ μ s (TYP.)
- Stable operation with 220 pF capacitive load
- Low input offset voltage and offset voltage null capability
 ± 2.5 mV (MAX.)
 ± 7 μ V/ $^{\circ}$ C (TYP.) temperature drift
- Very low input bias and offset currents
- Low noise : $e_n = 19$ nV/ $\sqrt{\text{Hz}}$ (TYP.)
- Output short circuit protection
- High input impedance ... J-FET Input Stage
- Internal frequency compensation

EQUIVALENT CIRCUIT



CONNECTION DIAGRAM (Top View)



ORDERING INFORMATION

| PART NUMBER | PACKAGE | QUALITY GRADE |
|---------------|-----------------------------|---------------|
| μ PC813C | 8 PIN PLASTIC DIP (300 mil) | Standard |
| μ PC813G2 | 8 PIN PLASTIC SOP (225 mil) | Standard |

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (T_a = 25 °C)

| PARAMETER | | SYMBOL | μPC813 | UNIT |
|--|---------------------|---------------------------------|--|------|
| Voltage between V ⁺ and V ⁻ (Note 1) | | V ⁺ - V ⁻ | -0.3 to +36 | V |
| Differential Input Voltage | | V _{ID} | ±30 | V |
| Input Voltage (Note 2) | | V _I | V ⁻ -0.3 to V ⁺ +0.3 | V |
| Output Voltage (Note 3) | | V _O | V ⁻ -0.3 to V ⁺ +0.3 | V |
| Power Dissipation | C Package (Note 4) | P _r | 350 | mW |
| | G2 Package (Note 5) | | 440 | mW |
| Output Short Circuit Duration (Note 6) | | | Indefinite | sec |
| Operating Temperature Range | | T _{opt} | -40 to +85 | °C |
| Storage Temperature Range | | T _{stg} | -55 to +125 | °C |

Note 1. Reverse connection of supply voltage can cause destruction.

Note 2. The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.

Note 3. This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.

Note 4. Thermal derating factor is -5.0 mW/°C when ambient temperature is higher than 55 °C.

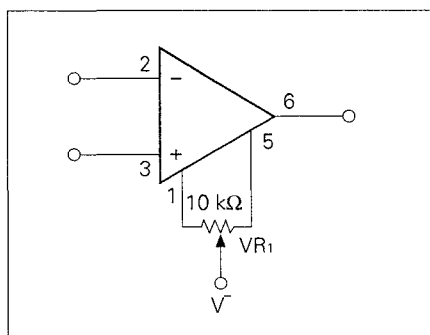
Note 5. Thermal derating factor is -4.4 mW/°C when ambient temperature is higher than 25 °C.

Note 6. Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4 and Note 5.

RECOMMENDED OPERATING CONDITIONS

| CHARACTERISTIC | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---|----------------|------|------|------|------|
| Supply Voltage | V [±] | ±5 | | ±16 | V |
| Output Current | I _o | | | ±10 | mA |
| Capacitive Load (A _v = +1, R _f = 0 Ω) | C _L | | | 220 | pF |

OFFSET VOLTAGE NULL CIRCUIT



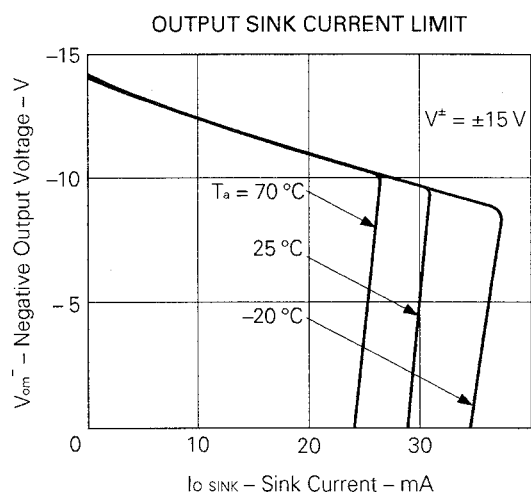
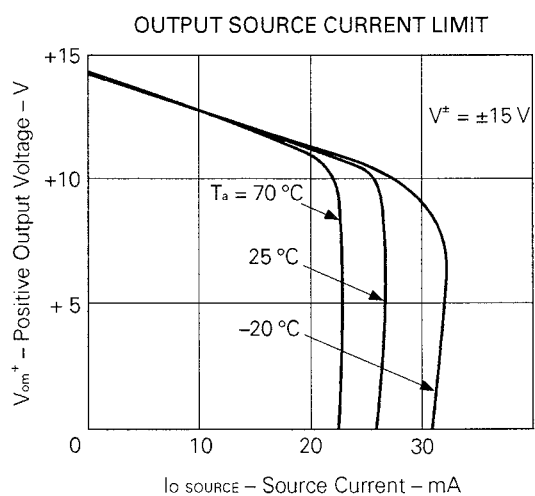
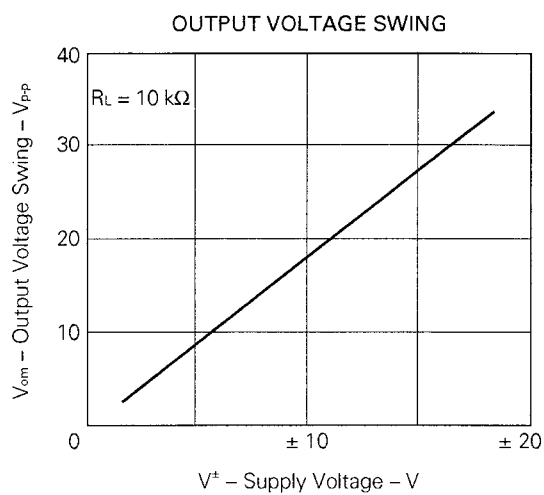
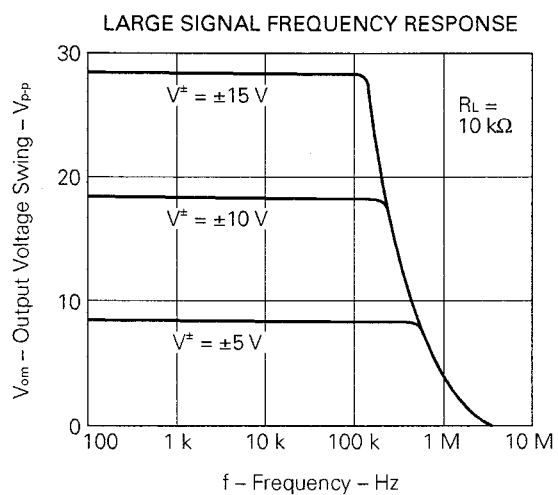
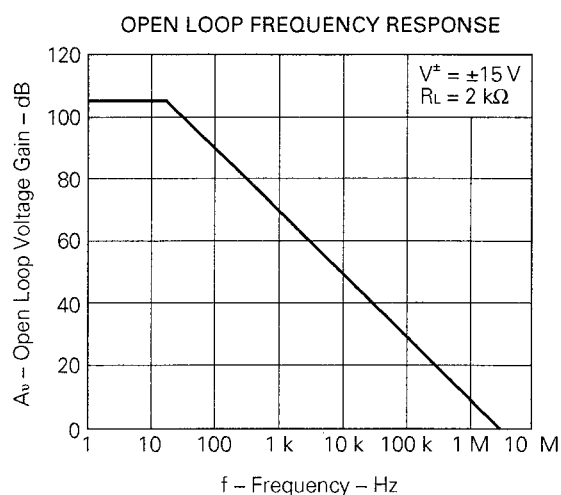
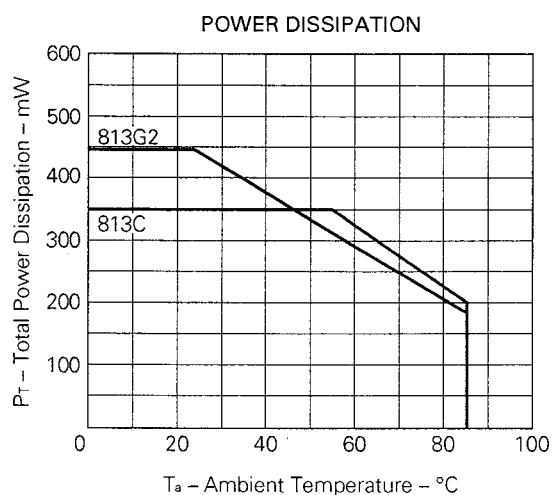
ELECTRICAL CHARACTERISTICS ($T_a = 25\text{ }^{\circ}\text{C}$, $V^{\pm} = \pm 15\text{ V}$)

| CHARACTERISTIC | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITION |
|--|--------------------------|----------|----------------|-----------|--------------------------------|---|
| Input Offset Voltage | V_{IO} | | ± 1 | ± 2.5 | mV | $R_s \leq 50\ \Omega$ |
| Input Offset Current (Note7) | I_{IO} | | ± 25 | ± 100 | pA | |
| Input Bias Current (Note7) | I_B | | 50 | 200 | pA | |
| Large Signal Voltage Gain | A_v | 25 | 200 | | V/mV | $R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{ V}$ |
| Supply Current | I_{CC} | | 2.5 | 3.4 | mA | $I_O = 0\text{ A}$ |
| Common Mode Rejection Ratio | CMR | 70 | 100 | | dB | |
| Supply Voltage Rejection Ratio | SVR | 70 | 100 | | dB | |
| Output Voltage Swing | V_{om} | ± 12 | +14.0 -13.3 | | V | $R_L \geq 10\text{ k}\Omega$ |
| Output Voltage Swing | V_{om} | ± 10 | +13.5 -12.8 | | V | $R_L \geq 2\text{ k}\Omega$ |
| Common Mode Input Voltage Range | V_{ICM} | ± 11 | +14 -12 | | V | |
| Slew Rate | SR | | 25 | | V/ μ s | $A_v = 1$ |
| Unity Gain Frequency | f_{unity} | | 6 | | MHz | |
| Input Equivalent Noise Voltage Density | e_n | | 19 | | nV/ $\sqrt{\text{Hz}}$ | $R_s = 100\ \Omega$, $f = 1\text{ kHz}$ |
| Input Offset Voltage | V_{IO} | | | ± 5 | mV | $R_s \leq 50\ \Omega$, $T_a = -20\text{ to }+70\text{ }^{\circ}\text{C}$ |
| Average V_{IO} Temperature Drift | $\Delta V_{IO}/\Delta T$ | | ± 7 | | $\mu\text{V}/^{\circ}\text{C}$ | $T_a = -20\text{ to }+70\text{ }^{\circ}\text{C}$ |
| Input Offset Current (Note7) | I_{IO} | | | ± 2 | nA | $T_a = -20\text{ to }+70\text{ }^{\circ}\text{C}$ |
| Input Bias Current (Note7) | I_B | | | 7 | nA | $T_a = -20\text{ to }+70\text{ }^{\circ}\text{C}$ |

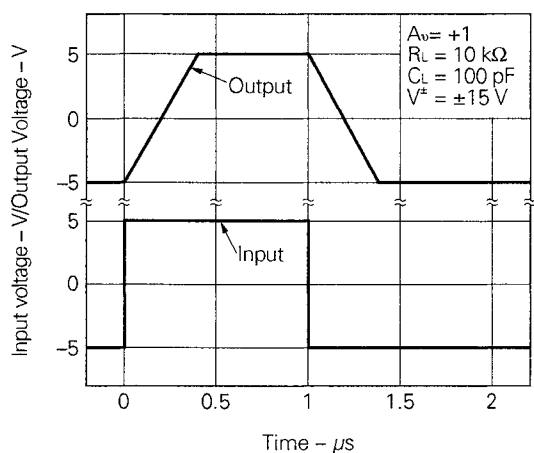
Note 7. Input bias currents flow into IC. Because each currents are gate leak current of P-channel J-FET on input stage.

And that are temperature sensitive. Short time measuring method is recommendable to maintain the junction temperature close to the ambient temperature.

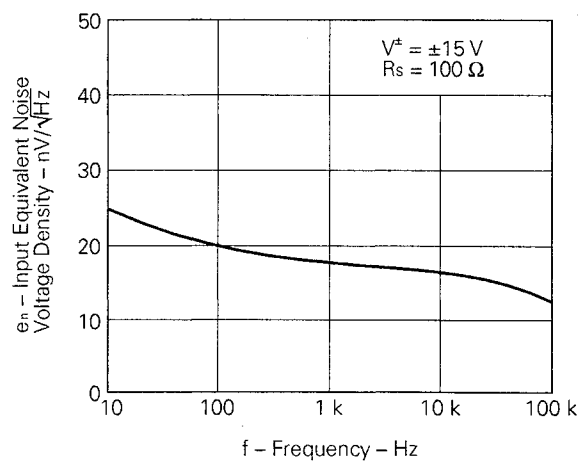
TYPICAL PERFORMANCE CHARACTERISTICS ($T_a = 25^\circ\text{C}$, TYP.)



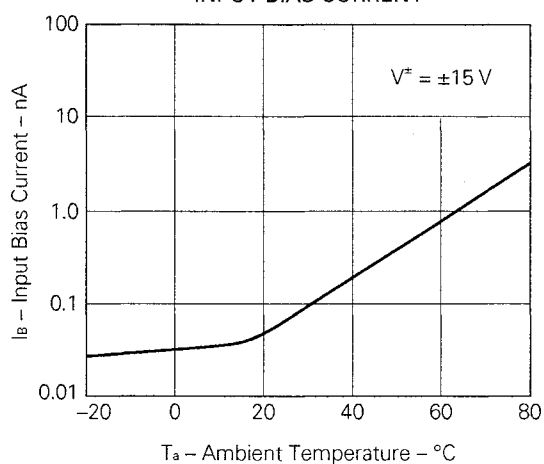
VOLTAGE FOLLOWER PULSE RESPONSE



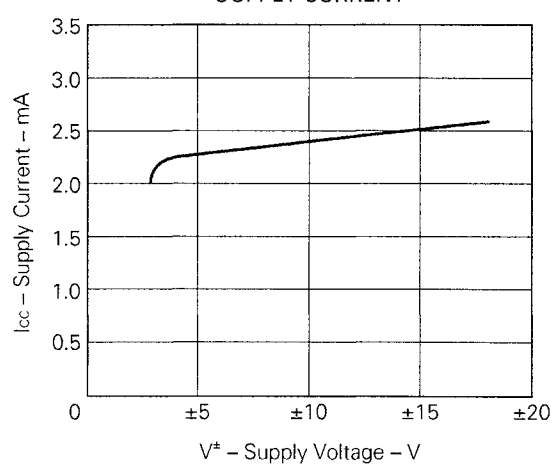
INPUT EQUIVALENT NOISE VOLTAGE DENSITY



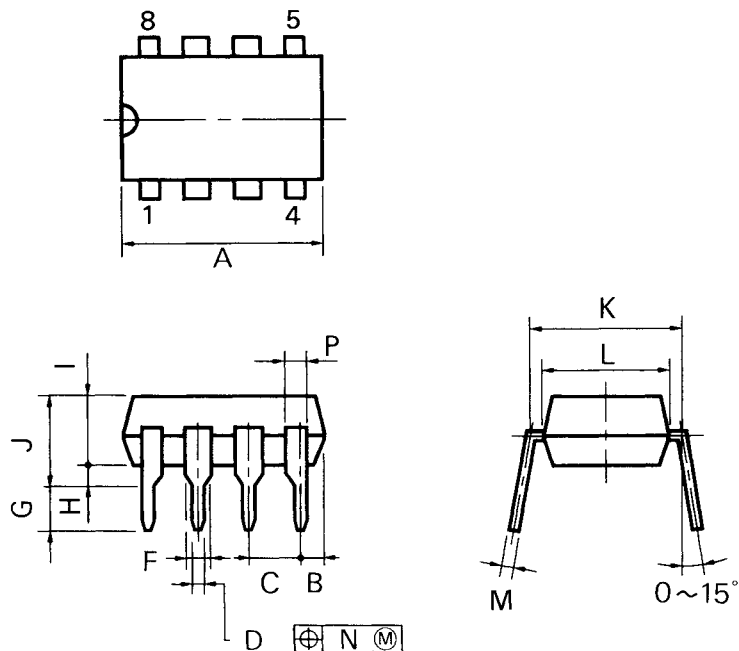
INPUT BIAS CURRENT



SUPPLY CURRENT



8PIN PLASTIC DIP (300 mil)



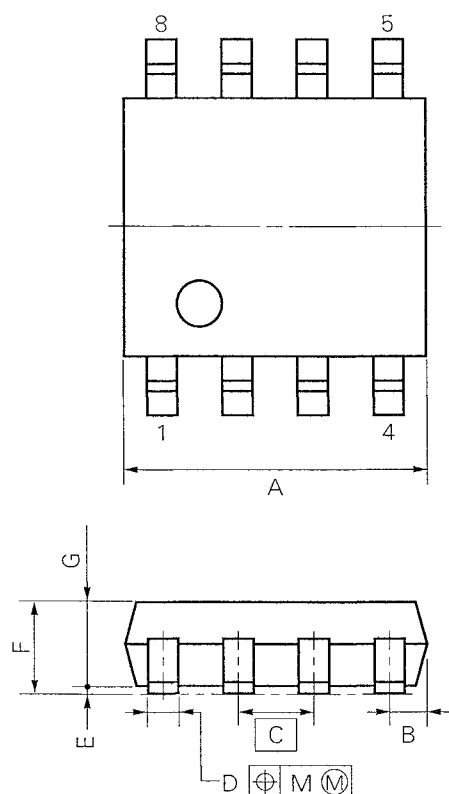
P8C-100-300B,C

NOTES

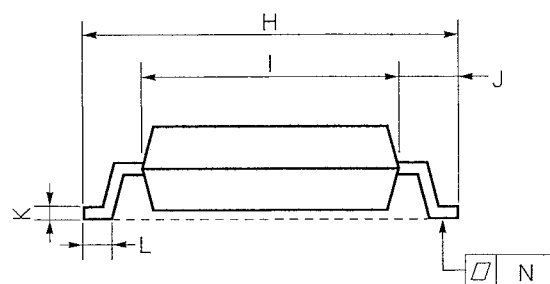
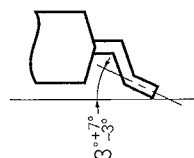
- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

| ITEM | MILLIMETERS | INCHES |
|------|---|--|
| A | 10.16 MAX. | 0.400 MAX. |
| B | 1.27 MAX. | 0.050 MAX. |
| C | 2.54 (T.P.) | 0.100 (T.P.) |
| D | 0.50 \pm 0.10 | 0.020 $\begin{smallmatrix} +0.004 \\ -0.005 \end{smallmatrix}$ |
| F | 1.4 MIN. | 0.055 MIN. |
| G | 3.2 \pm 0.3 | 0.126 \pm 0.012 |
| H | 0.51 MIN. | 0.020 MIN. |
| I | 4.31 MAX. | 0.170 MAX. |
| J | 5.08 MAX. | 0.200 MAX. |
| K | 7.62 (T.P.) | 0.300 (T.P.) |
| L | 6.4 | 0.252 |
| M | 0.25 $\begin{smallmatrix} +0.10 \\ -0.05 \end{smallmatrix}$ | 0.010 $\begin{smallmatrix} +0.004 \\ -0.003 \end{smallmatrix}$ |
| N | 0.25 | 0.01 |
| P | 0.9 MIN. | 0.035 MIN. |

8 PIN PLASTIC SOP (225 mil)



detail of lead end



NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

S8GM-50-225B-2

| ITEM | MILLIMETERS | INCHES |
|------|--|---|
| A | 5.37 MAX. | 0.212 MAX. |
| B | 0.78 MAX. | 0.031 MAX. |
| C | 1.27 (T.P.) | 0.050 (T.P.) |
| D | 0.40 ^{+0.10} _{-0.05} | 0.016 ^{+0.004} _{-0.003} |
| E | 0.1±0.1 | 0.004±0.004 |
| F | 1.8 MAX. | 0.071MAX. |
| G | 1.49 | 0.059 |
| H | 6.5±0.3 | 0.256±0.012 |
| I | 4.4 | 0.173 |
| J | 1.1 | 0.043 |
| K | 0.15 ^{+0.10} _{-0.05} | 0.006 ^{+0.004} _{-0.002} |
| L | 0.6±0.2 | 0.024 ^{+0.008} _{-0.009} |
| M | 0.12 | 0.005 |
| N | 0.15 | 0.006 |

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI-1207).

[μ PC813G2]

| Soldering method | Soldering conditions | Recommended condition symbol |
|------------------------|--|------------------------------|
| Infrared ray reflow | Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None | IR30-00-1 |
| VPS | Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None | VP15-00-1 |
| Wave soldering | Solder temperature: 260 °C or below, Flow time: 10 seconds or below, Number of flow process: 1, Exposure limit*: None | WS15-00-1 |
| Partial heating method | Terminal temperature: 300 °C or below, Flow time: 10 seconds or below, Exposure limit*: None | |

*: Exposure limit before soldering after dry-pack package is opened.

Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method."

TYPES OF THROUGH HOLE DEVICE

[μ PC813C]

| Soldering method | Soldering conditions | Recommended condition symbol |
|------------------|--|------------------------------|
| Wave soldering | Solder temperature: 260 °C or below, Flow time: 10 seconds or below | |

[MEMO]

[MEMO]

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